



LA6531

Monolithic Linear IC

2-Channel BTL-Use Drivers

Overview

The LA6531 are 2-channel BTL-use drivers designed for compact disc pickup actuation.

Functions and Features

- High output current (I_O max = 0.7A).
- Wide operating voltage range (4 to 15V).
- Low input bias current.
- Output of amps 1 to 4 and buffer amplifier at muting-ON mode : OFF

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max		16	V
Differential input voltage	V_{ID}	Amplifier 2, amplifier 3	15	V
Common-mode input voltage	V_{ICM}	Amplifier 2, amplifier 3	15	V
Maximum input voltage	V_{INB} max	Buffer amplifier	15	V
Maximum flow-in current at muting pin	I_M max		1.0	mA
Maximum output current	I_O max		0.7	A
Allowable power dissipation	P_d max		1.9	W
Operating temperature	T_{opr}		-20 to +75	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application" intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment, etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

LA6531

Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max		5	V
Load resistance	R_L		8	Ω

Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 5.0\text{V}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
No-loaded current drain 1	I_{CC1}	Mute OFF, pins 8, 9, 16 GND	5	10	20	mA
No-loaded current drain 2	I_{CC2}	Mute OFF, pins 8, 9, 16 GND	3	7	15	mA
No-loaded current drain 3	I_{CC3}	Mute OFF, pins 8, 9, 16 $1/2 V_{CC}$	10	20	30	mA
No-loaded current drain 4	I_{CC4}	Mute OFF, pins 8, 9, 16 $1/2 V_{CC}$	4	8	16	mA
Output offset voltage 1	V_{OF1}	Out 1 - Out 2	-50		+50	mV
Output offset voltage 2	V_{OF2}	Out 4 - Out 3	-50		+50	mV
Buffer input-output voltage difference	V_{BIO}	Buffer amplifier	-30		+30	mV
Buffer input voltage range	V_{BICM}	Buffer amplifier	1.5		$V_{CC} - 1.5$	V
Common-mode input voltage range	V_{ICM}	Amplifier 2, amplifier 3	1.0		$V_{CC} - 1.5$	V
Input bias current	I_B			50	300	nA
Output voltage	V_O	$R_L = 8.0 \Omega$	2.8	3.3		V
Bridge output voltage difference	V_{OD}	Pins 3-6, 11-14 8Ω load	1.8	2.2		V
Closed-circuit voltage gain	V_G		30	38		dB
Muting pin ON-state voltage	V_M			0.7		V
Muting pin flow-in current	I_M			3		μA

Note) With thermal shutdown function

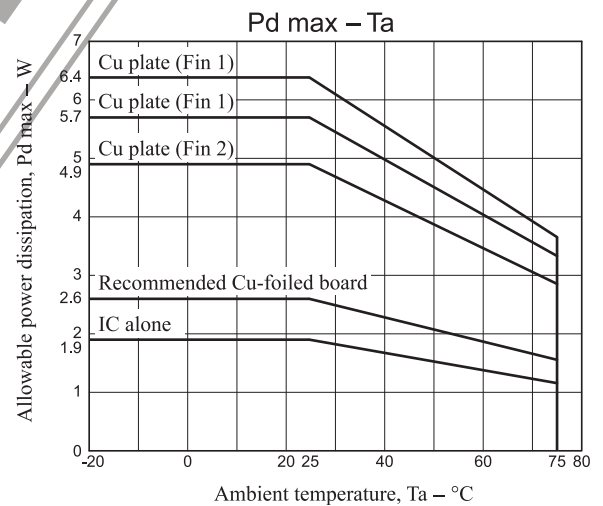
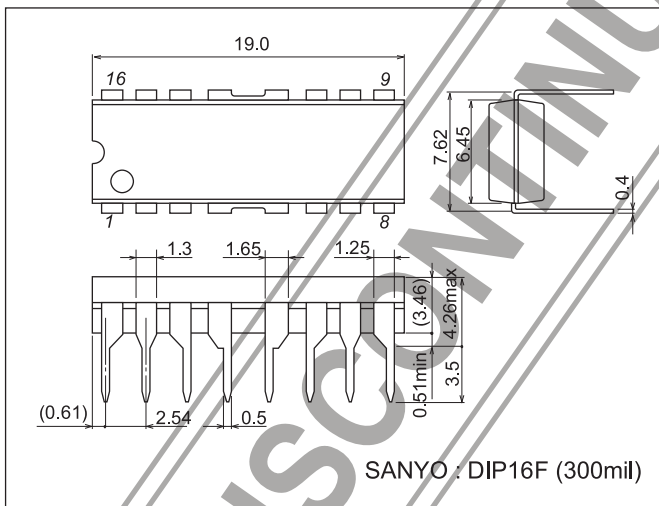
* : The LA6531 is so designed that the outputs at OUT1 to OUT4 and the output at VBOUT are turned OFF.

* : Be carefull in handling the LA6531, because dielectric breakdown is liable to occur.

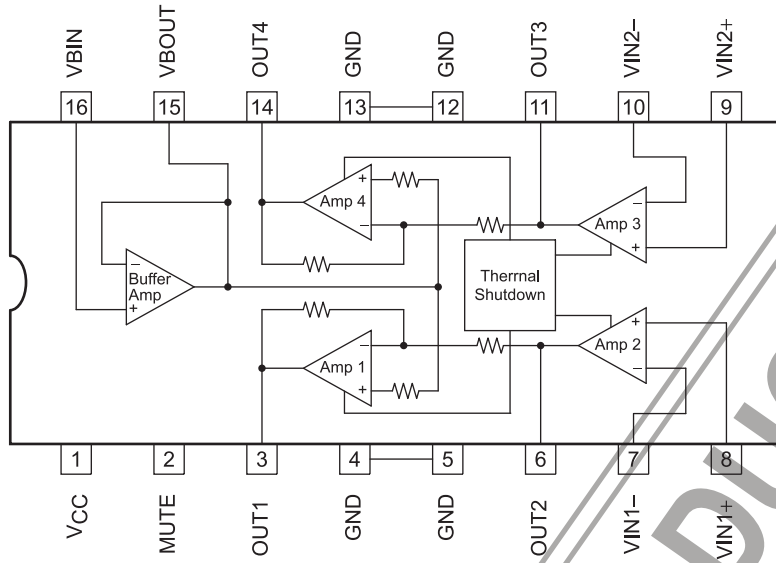
Package Dimensions

unit : mm (typ)

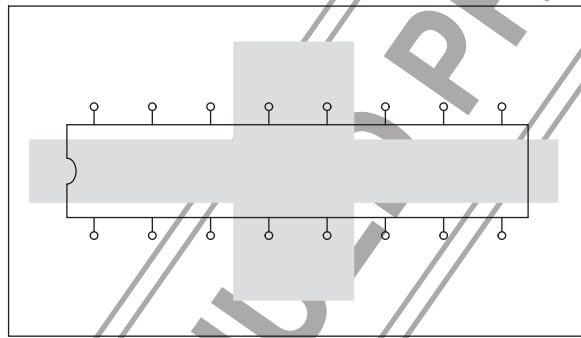
3054B



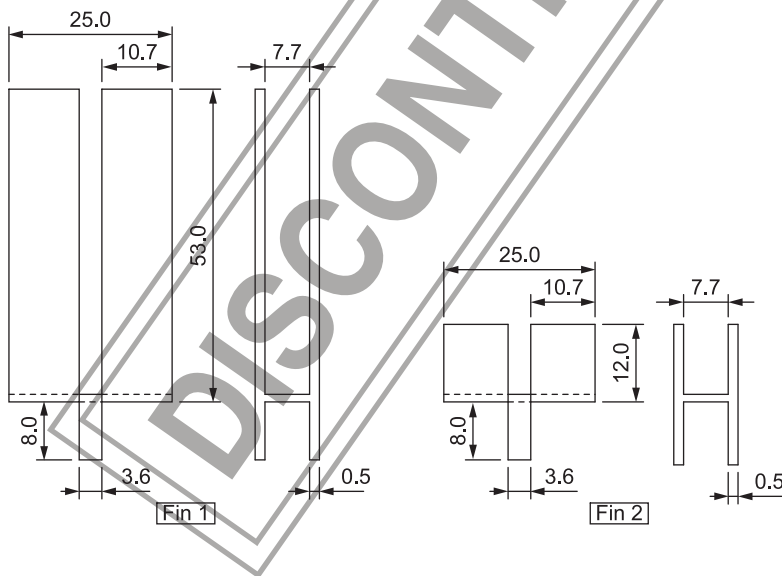
Block Diagram



Sample Printed Circuit Pattern



Cu-foiled area 80×60mm²



UNVALUED PRODUCT

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of June, 2008. Specifications and information herein are subject to change without notice.